

Surface Mount High Efficiency Power Rectifiers

Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes in surface mount applications where compact size and weight are critical to the system.

- * Low Power Loss, High efficiency
- * Glass Passivated chips junction
- * 150 °C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction
- * Low Forward Voltage Drop , High Current Capability
 * High-Switching Speed 50 & 75 Nanosecond Recovery Time
- * Small Compact Surface Mountable Package with J-Bend Lead
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

MAXIMUM RATINGS

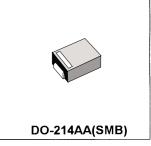
| Characteristic | Symbol | MH11 | MH12 | MH13 | MH14 | MH15 | Unit |
|--|--|---------------|------|------|------|------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 50 | 100 | 200 | 300 | 400 | V |
| RMS Reverse Voltage | V _{R(RMS)} | 35 | 70 | 140 | 210 | 280 | ٧ |
| Average Rectifier Forward Current | l _o | | | 1.0 | | | Α |
| Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware,single phase,60Hz) | FSM | 30 | | | Α | | |
| Operating and Storage Junction Temperature Range | T _j , T _{stg} | - 65 to + 150 | | °C | | | |

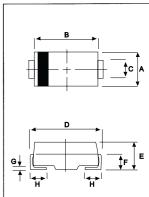
ELECTRICAL CHARACTERISTICS

| Characteristic | Symbol | MH11 | MH12 | MH13 | MH14 | MH15 | Unit |
|--|-----------------|------|------|-----------|------|------|------|
| Maximum Instantaneous Forward Voltage $(I_F=1.0 \text{ Amp}, T_C=25 ^{\circ}\text{C})$ | V _F | | 1.00 | | 1. | 30 | V |
| Maximum Instantaneous Reverse Current (Rated DC Voltage, T _c = 25 °C) (Rated DC Voltage, T _c = 125 °C) | I _R | | | 5.0 50 | | | uA |
| Reverse Recovery Time (I _F = 0.5 A, I _R =1.0 , I _{rr} =0.25 A) | T _{rr} | | 50 | | 7 | 5 | ns |
| Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz) | C _P | | 25 | | 2 | :0 | pF |

HIGH EFFICIENCY RECTIFIERS

1.0 AMPERES 50 -- 400 VOLTS



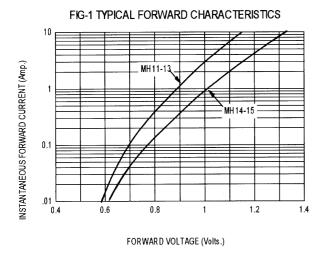


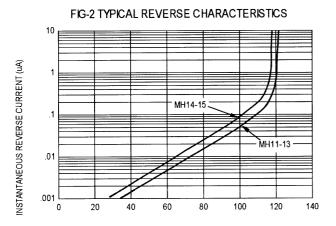
| DIM | MILLMETERS | | | | | |
|---------------|--------------------------------------|--|--|--|--|--|
| | MIN | MAX | | | | |
| A B C D E F G | 3.30 4.20 1.80 4.90 1.90 | 3.90 4.60 2.20 5.60 2.50 1.30 0.22 | | | | |
| Н | 0.85 | 1.45 | | | | |

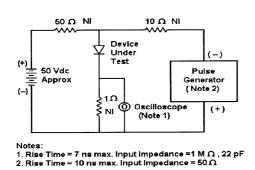
CASE---

Transfer molded plastic

POLARITY---Cathode indicated polarity band







PERCENT OF PEAK REVERSE VOLTAGE(%)

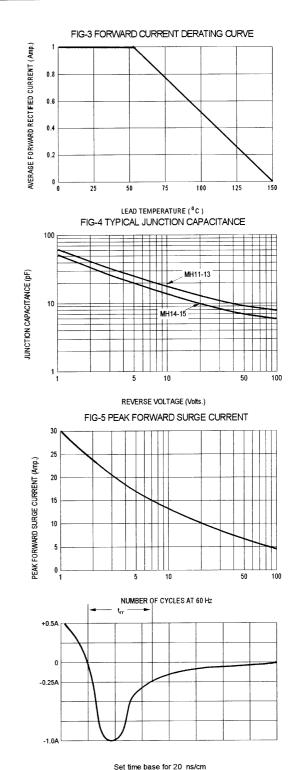


Fig-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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